

# SubGeV Dark Matter searches with EDELWEISS

C. Nones

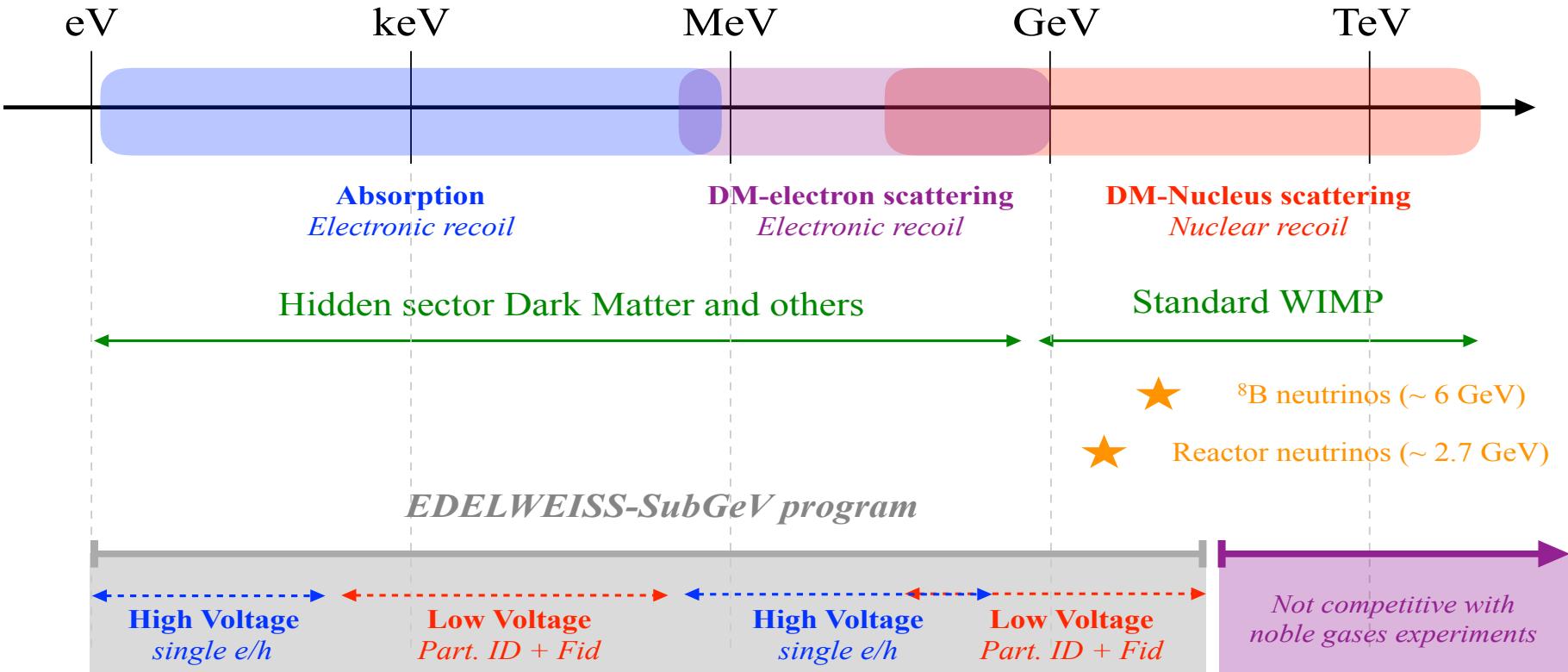
on behalf of the EDELWEISS collaboration

# Outline

- The scientific context
- EDELWEISS-III : setup & FID detectors
- From EDW-III to EDW-SubGeV
  - Axion-like limits
  - Above-ground activities: EDW-Surf
  - LSM results: EDW R&D
- Conclusions and Prospectives

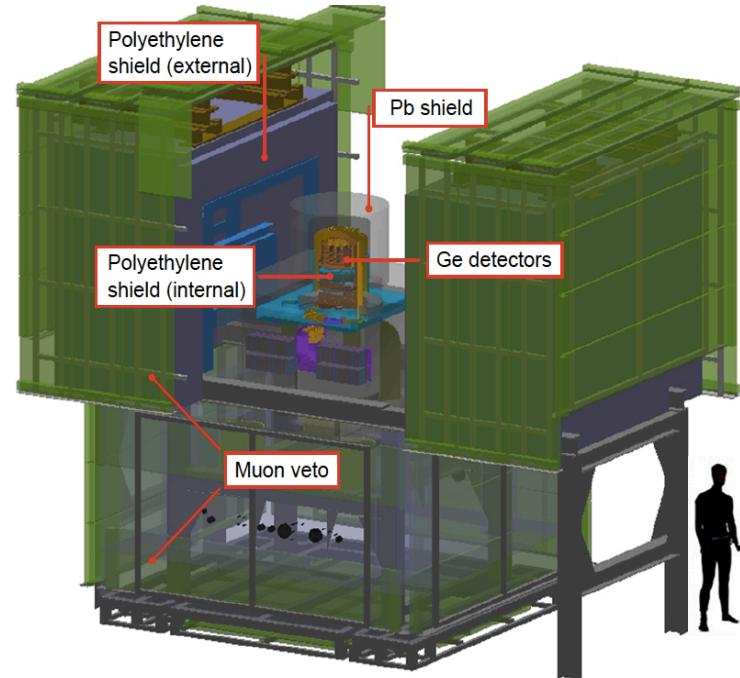
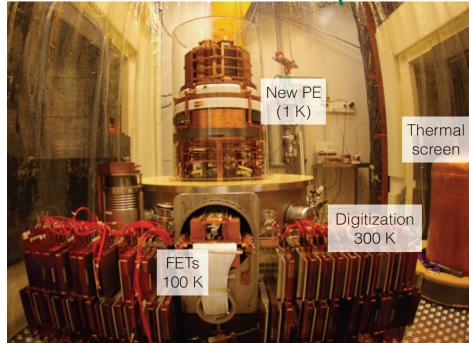


# The scientific context



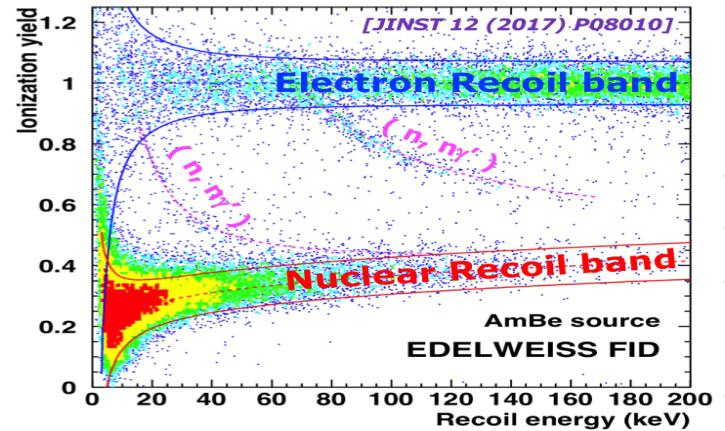
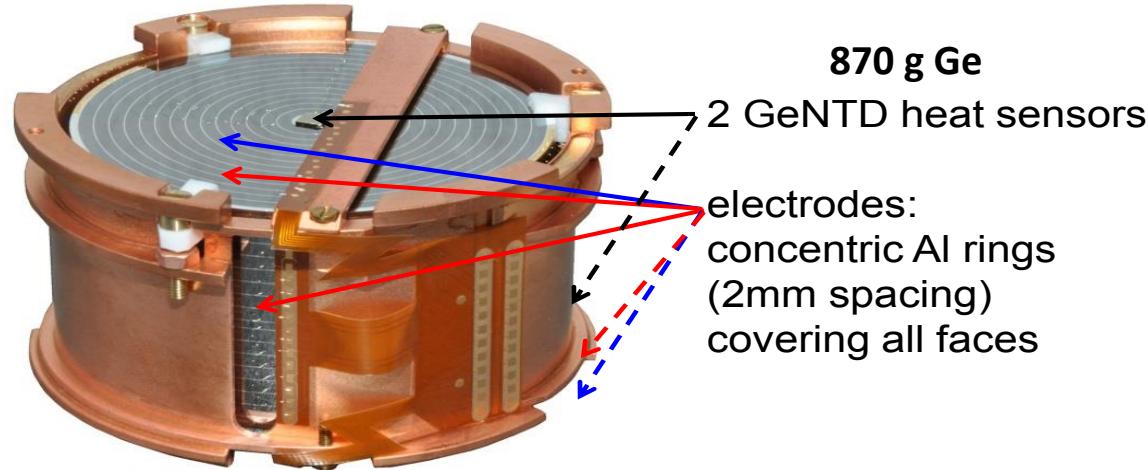
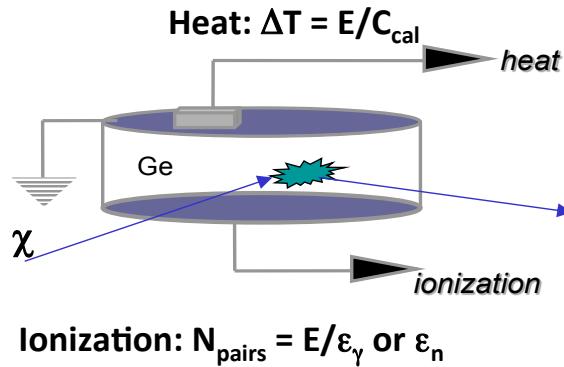
# The EDELWEISS setup

- **LSM: Deepest site in Europe: 4800 m.w.e.,  $5 \mu\text{m}^2/\text{day}$**
- Clean room + deradonized air  
*Radon monitoring down to few mBq/m<sup>3</sup>*
- Active muon veto (>98% coverage) on mobile shield
- External (50 cm) + internal polyethylene shielding  
*Thermal neutron monitoring with <sup>3</sup>He detector*
- Lead shielding (20 cm, including 2 cm Roman lead)
- Selection of radiopure material



*Performance of the EDELWEISS-III experiment for direct dark matter searches  
[JINST 12 (2017) P08010]*

# The EDELWEISS-III detectors



$\varnothing=70\text{mm}$ ,  $h=40\text{ mm}$

Operated at  
 $T = 18\text{ mK}$

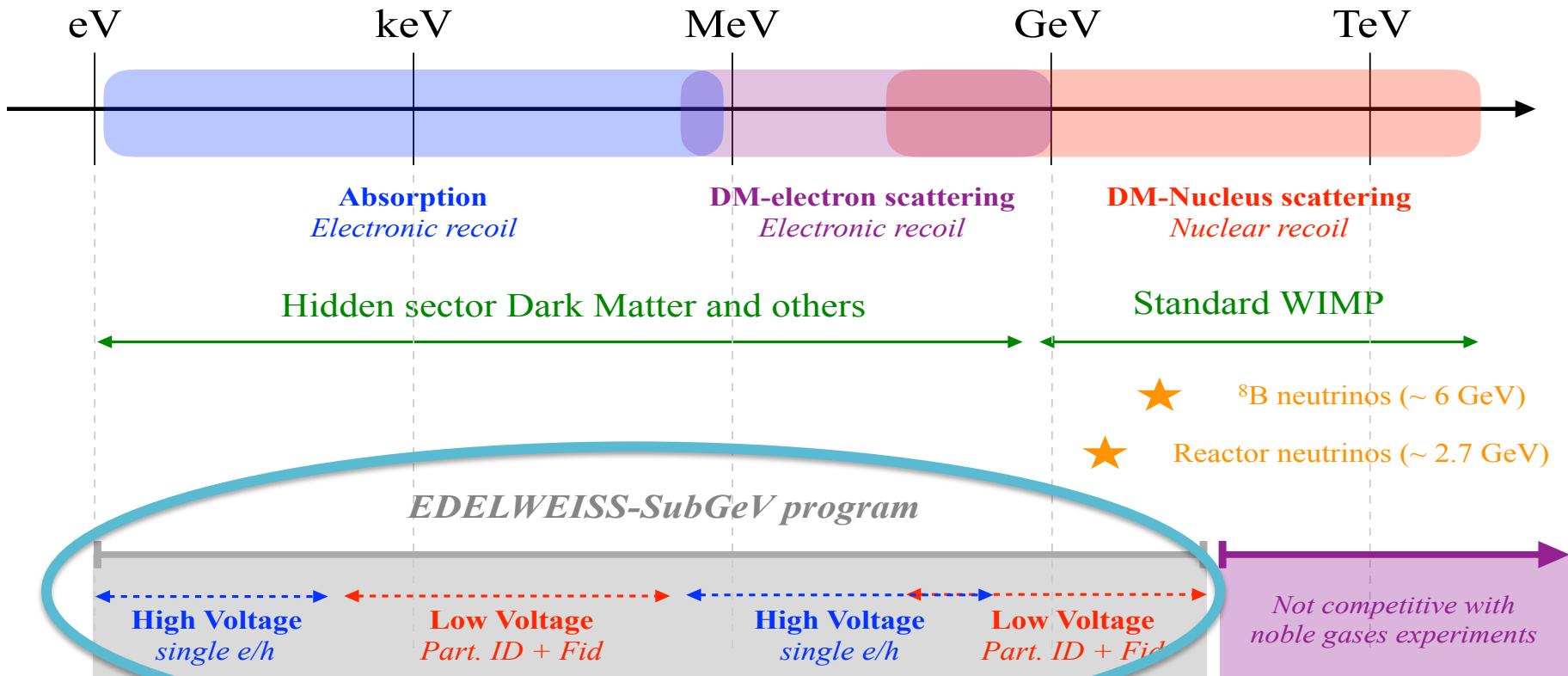
## Ionization:

- $\varepsilon_\gamma = 3\text{ eV}/(\text{e-hole pair})$  for electron recoils ( $\gamma, \beta$ )
- $\varepsilon_n \sim 12\text{ eV}/(\text{e-hole pair})$  for nuclear recoils (neutrons, WIMPs)
- $\varepsilon_\gamma/\varepsilon_n = \text{ionization quenching } Q \rightarrow E_{\text{ion}} = Q E_{\text{recoil}}$  in keV<sub>ee</sub>

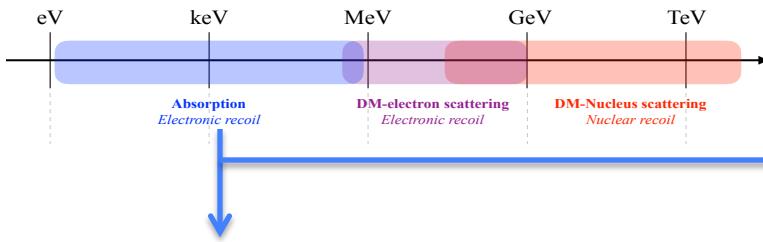
## Heat:

- direct measurement of ALL the energy, irrespective of particle ID

# The EDELWEISS SubGeV programme



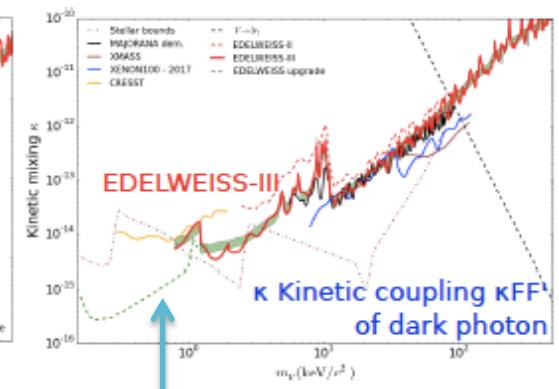
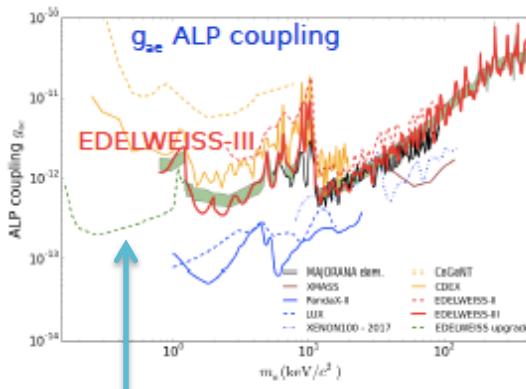
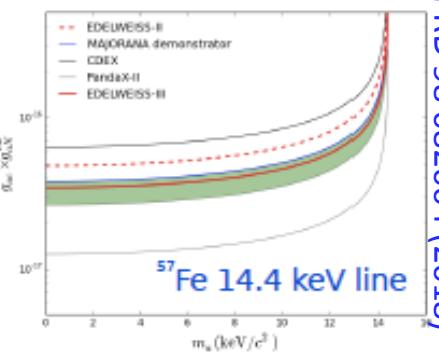
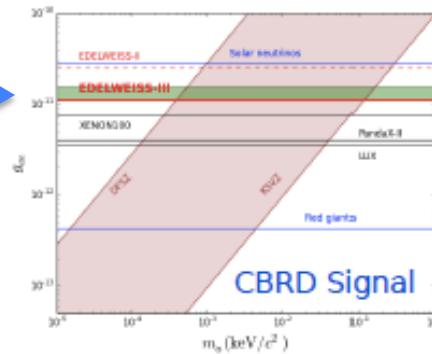
# Electron recoil analysis: axion-like limits



## Absorption of keV-scale Bosonic DM

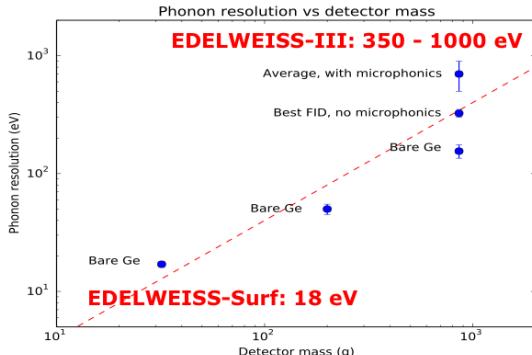
- Best Ge-based limit < 6 keV (thanks to surface rejection)
- Start to explore < 1 keV
- Surface rejection (i.e. ionization resolution) very important to reduce low-energy ER backgrounds
- Improvements foreseen in the 100 eV – 1 keV region with improved ionization (here:  $\sigma = 35 \text{ eV}_{\text{ee}}$  with HEMT readout)

## Emission of axions/ALPs from the Sun

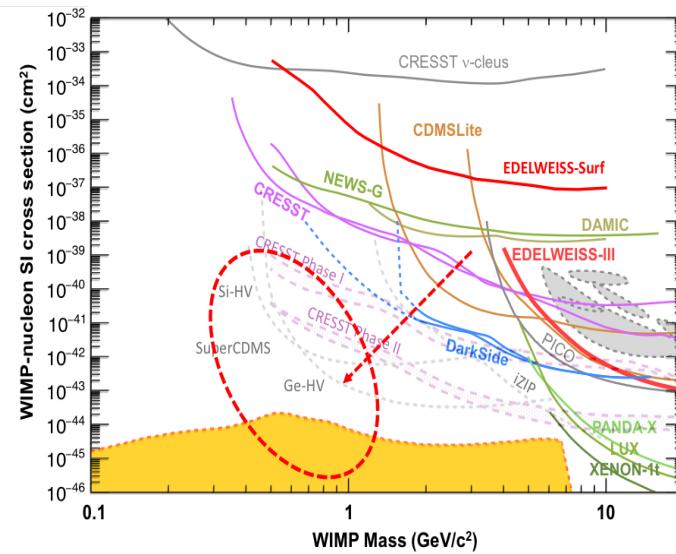




- Current+future projects: background limited
- Event-by-event rejection even at 1 GeV/c<sup>2</sup> and 10<sup>-43</sup> cm<sup>2</sup> requires a new generation of detectors
- An event-by-event rejection with ~1 kg.y requires  $\sigma_{\text{phonon}} = 10 \text{ eV}$  and  $\sigma_{\text{ion}} = 20 \text{ eV}_{ee}$



# EDELWEISS SubGeV program



- Keeping the ability to apply HV to EDELWEISS detectors is important to reduce thresholds in ER searches
  - For NR: depends a lot on quenching
- Reducing the detector from 860 to 33 g is worth it if the resolution goals are met



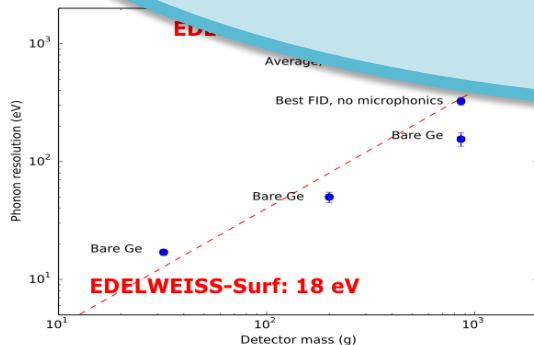
- Current+future projects:

### 3 main pillars to be reached by the EDELWEISS detectors

- Energy resolution :  $10\text{ eV}$  (RMS)
- EM background rejection (LV mode)  $> 10^3$  :  $20\text{ eV}$
- Operation at high voltages (HV mode):  $100\text{V}$

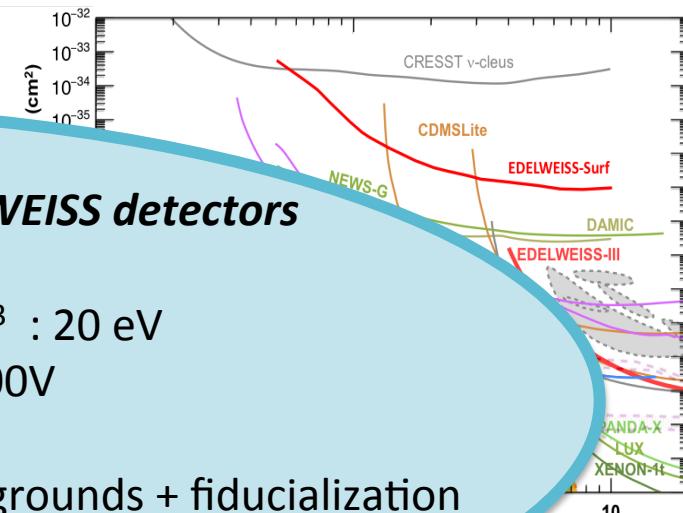
### Two running modes

- **Low Voltage**: Particle ID – ER/NR/ unknown backgrounds + fiducialization
- **High Voltage**: single e/h sensitivity thanks to the Neganov-Luke mode



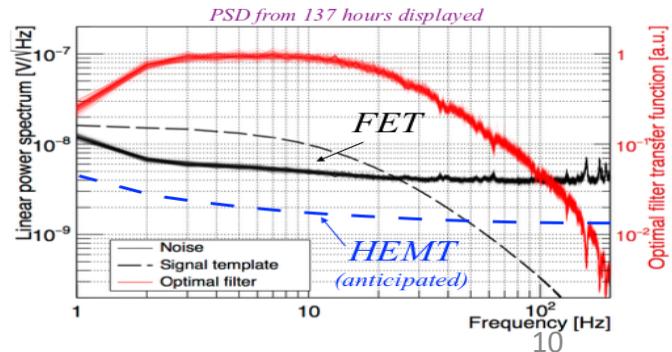
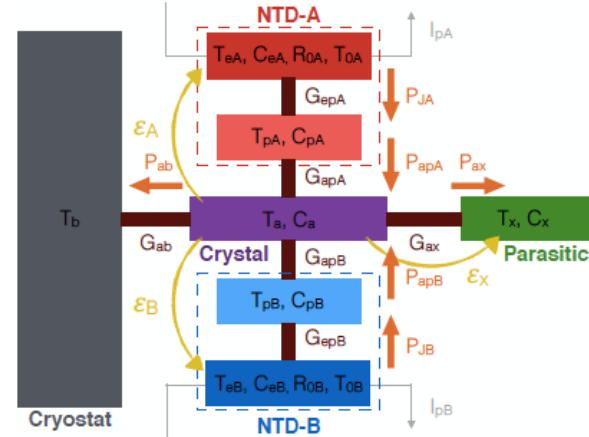
The EDELWEISS detectors is  
able to reach the best thresholds in ER searches

- For NR: depends a lot on quenching
- Reducing the detector from  $860$  to  $33\text{ g}$  is worth it if the resolution goals are met



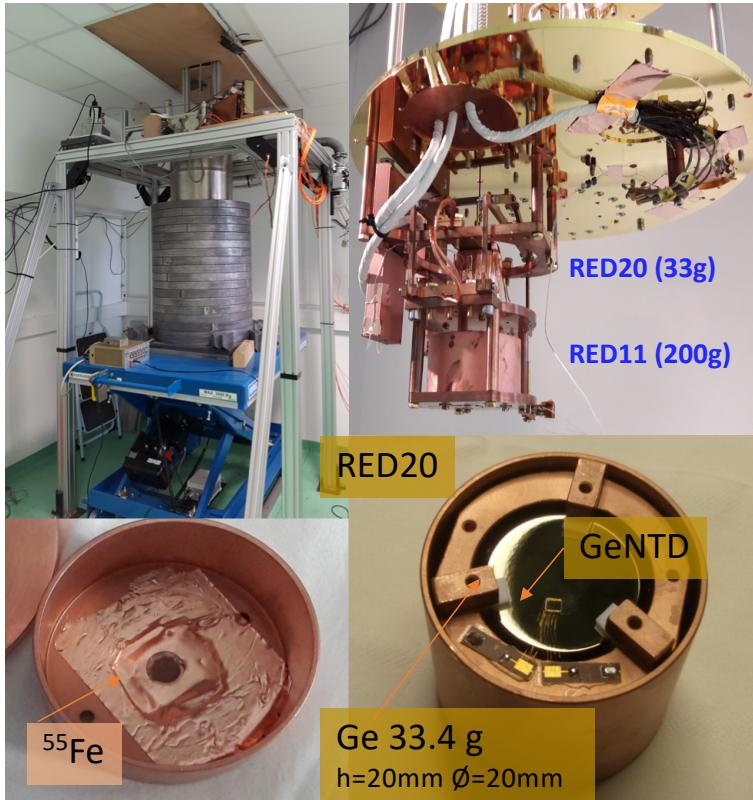
# How to reach 10 eV phonon resolution

- Intense above ground R&D on NTD sensor
- Development of a detailed thermal model for the heat channel to optimise the choice of the best configuration
- Test of different glues
- Investigation of alternative sensors: NbSi TES
- Limited by FET current noise: replacing JFETs @ 100K with HEMTs @ 1K should provide additional x2 needed in resolution



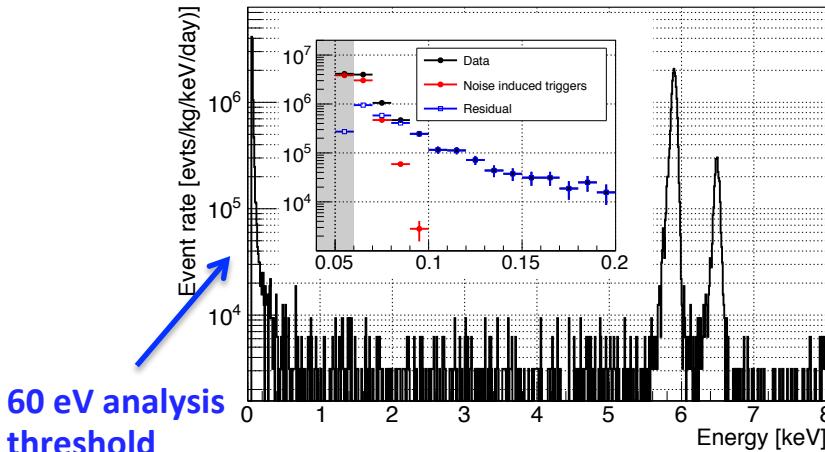
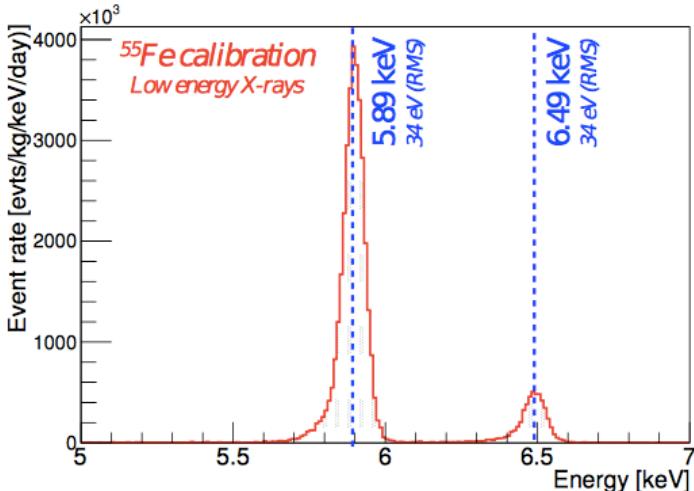
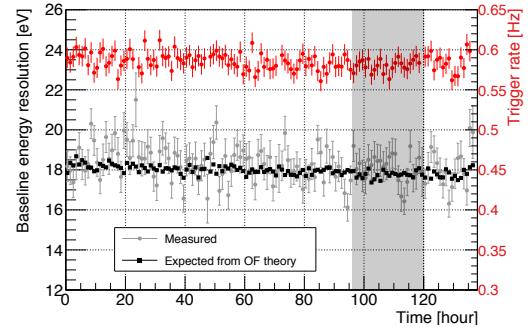
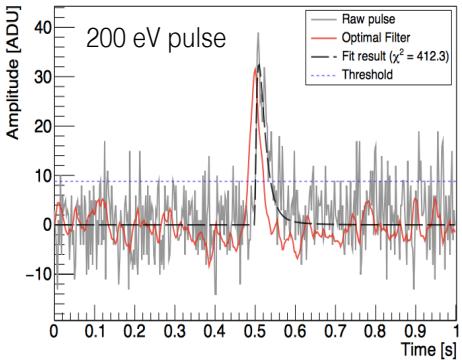
# EDELWEISS-Surf: an above-ground DM search

- Easy-access surface lab @ IPN-Lyon
- <1 m overburden: ideal for SIMP search (strongly interacting DM)
- Dry cryostat (CryoConcept) with <30h cool-down (fast turnover ideal for detector R&D)
- Vibration mitigation: <  $\mu\text{g}/\sqrt{\text{Hz}}$  vibration levels obtained in spring-suspended tower
- RED20: 33.4 g Ge with NTD sensor, with no electrode
  - No ER/NR discrimination, but no uncertainty due to ionization yield or charge trapping
- Low energy calibration:
  - $^{55}\text{Fe}$  x-ray source for calibration
  - Ge neutron activation
- Small 0.03 kg.day exposure



# Pulses, calibration, resolution and energy spectrum

- Optimal filter fit to pulses
- Stability of noise & resolution over 137h of data taking
- 1 day set aside a priori for blind search
- **Baseline:  $\sigma = 17.8 \text{ eV}$**



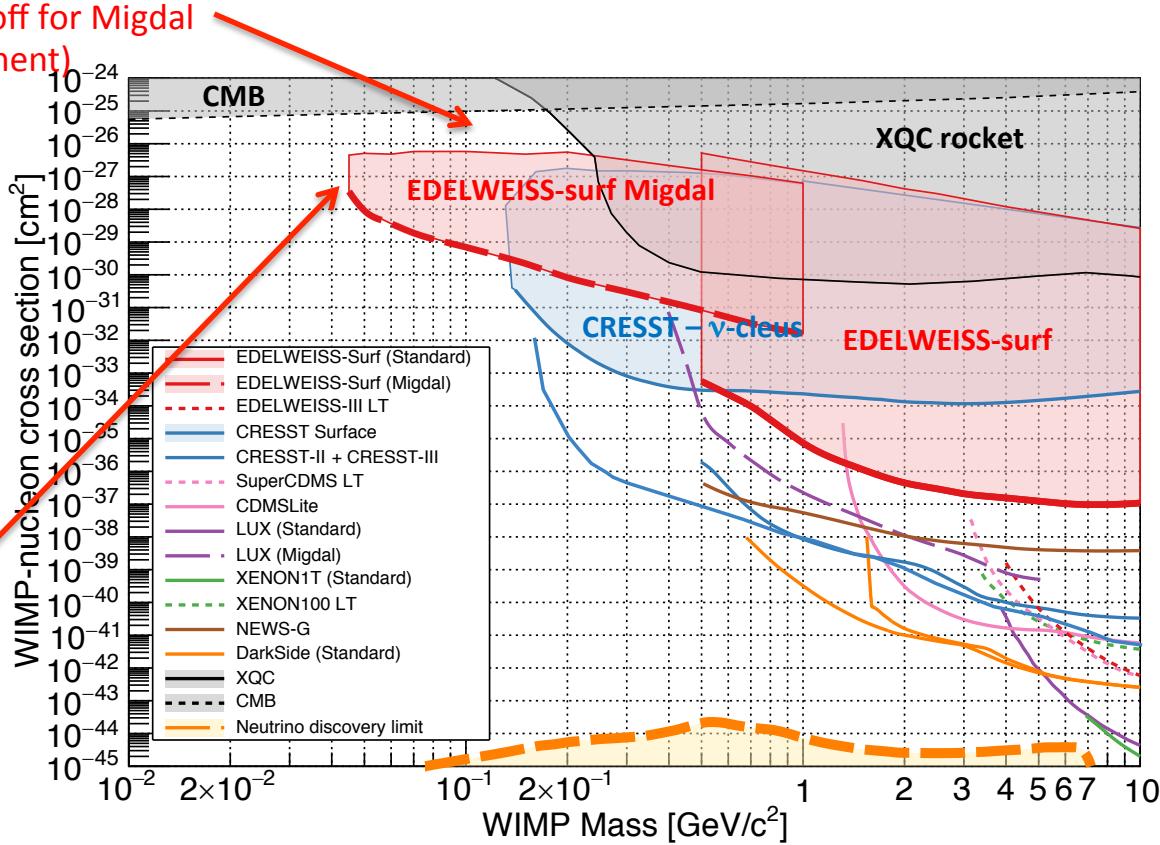
# Filling the SubGeV region

Stronger upper cutoff for Migdal  
(subleading component)

## DM – nucleus interaction

- First Ge-based limit below 1.2 GeV and best above-ground limit down to 600 MeV (SIMPs)
- Considering Migdal effect: first DM limit down to 45 MeV limited by Earth-Shielding effect

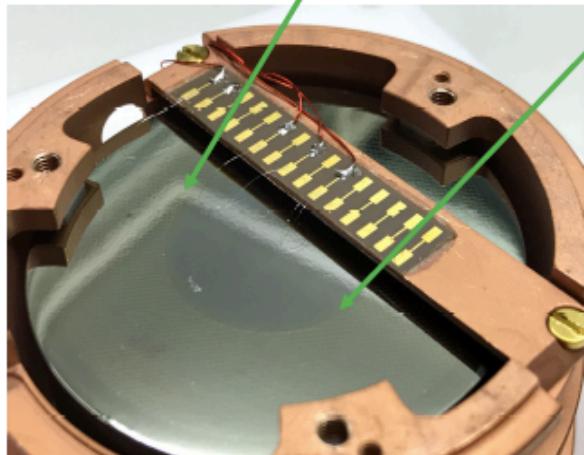
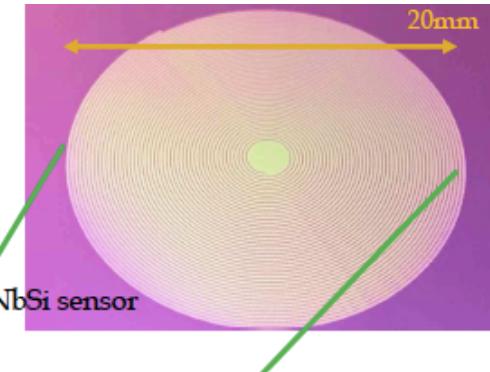
Sharp 45 MeV/c<sup>2</sup> cutoff  
due to ES effect on  
velocity



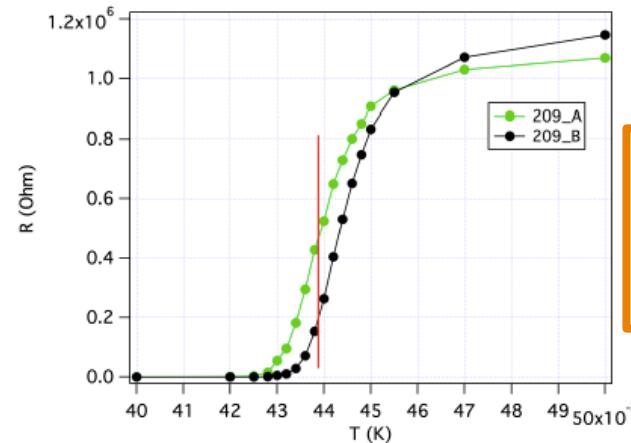
# 10 eV with high impedance NbSi TES sensor

## NbSi209 @ LSM

100mm thick, 20mm diameter  
spiral NbSi sensor  
Lithography  
On a 200 g HP-Ge crystal (48 x  
20 mm)



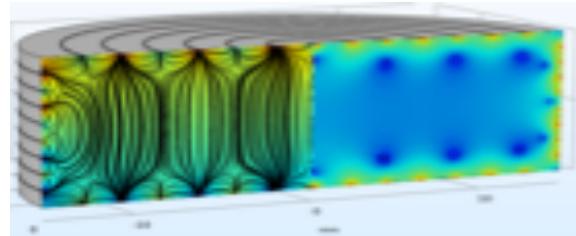
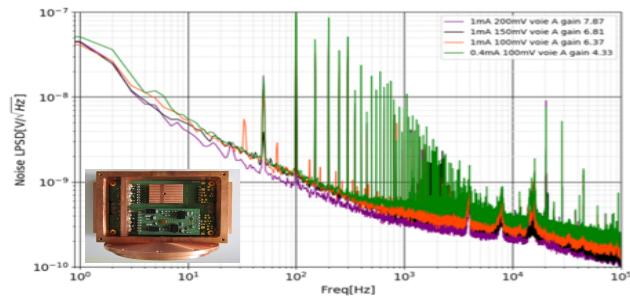
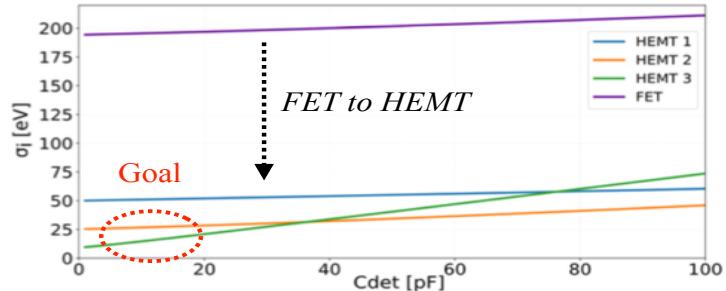
NbSi TES: alternative sensor for the heat channel  
 $\text{Nb}_x\text{Si}_{1-x}$ : amorphous compound  
 $x > 13\% \rightarrow$  superconductor  
Directly done by lithography on the crystal or on sapphire/germanium chip  
High impedance – compatible with standard JFET  
Goal: 10 eV RMS



330 nV/keV on A, 658 nV/keV on B  
Phonon:  $\sigma_A = 183$  eV,  $\sigma_B = 125$  eV  
Combined:  
 $\sigma = 113$  eV or  $5\text{eV}_{ee}$  @ 66V

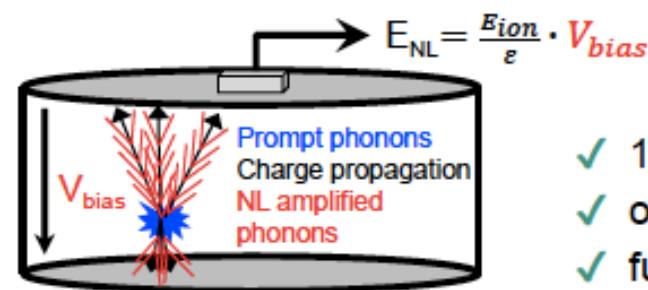
# How to reach 20 eV ionization resolution

- Transition from JFET to HEMT (as initiated by the CDMS-Berkeley group, arXiv:1611.09712)
- Lower intrinsic noise than JFET
- Reduction of the stray capacitance by working at 1K or 4K
- Thanks to a data driven HEMT model, the goal of 20 eV<sub>ee</sub> is reachable with ~20 pF total input impedance
- Ongoing HEMT characterizations
- HEMT-based preamp tests foreseen by end of 2019
- Cryogenics + cabling challenges ahead

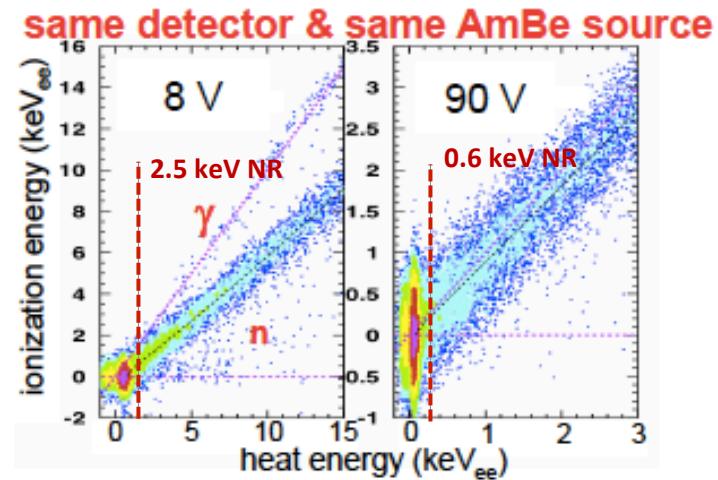
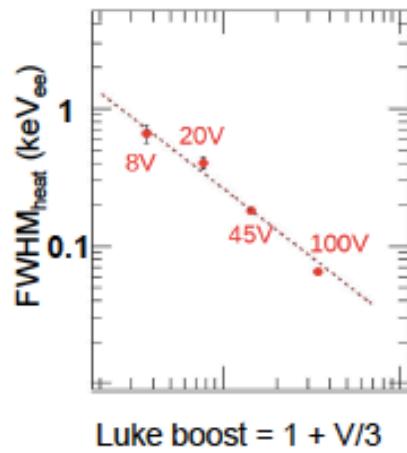
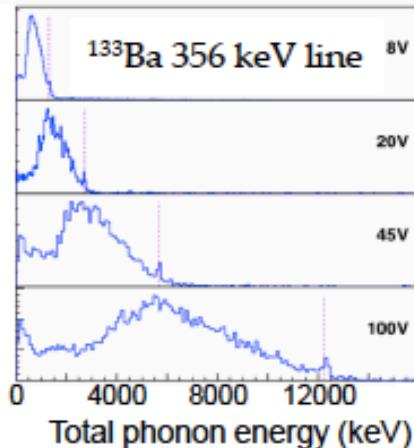


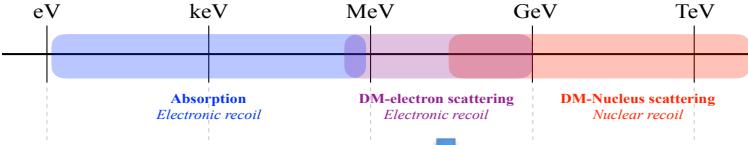
Optimization of 38g FID design: large fiducial volume & low capacitance

# How to reach 100V with Neganov-Luke boost



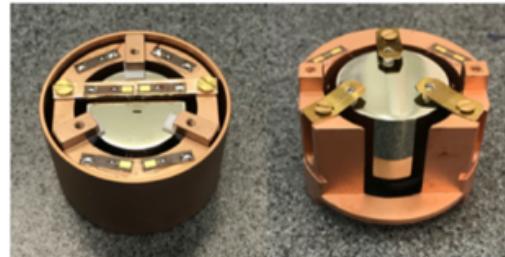
- ✓ 100 V on detector already achieved
- ✓ observe nuclear recoils down to  $\sim 0.1$  keV<sub>ee</sub>
- ✓ full ion.+heat readout possible at any V



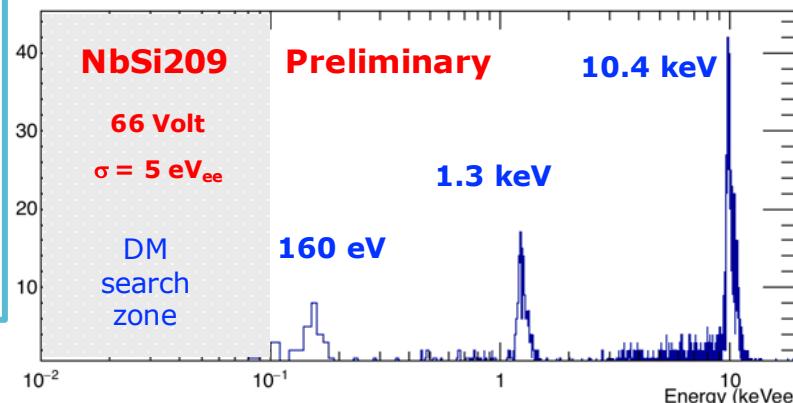


# High voltage operation @ LSM

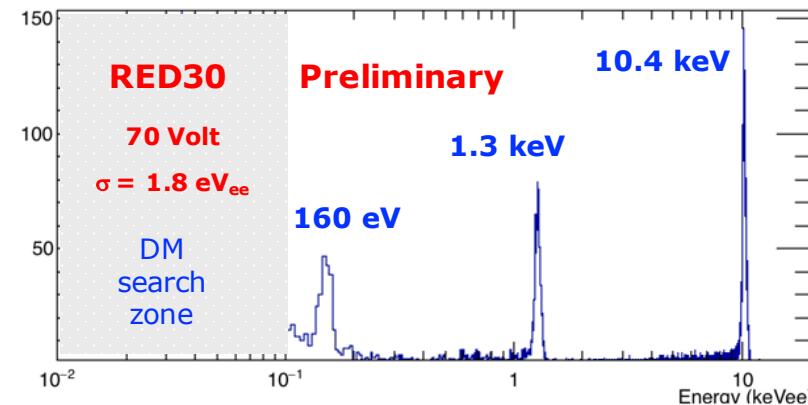
Exploring DM-electron/nucleus interactions with *near* single-electron sensitivity achieved in massive bolometers operated underground @LSM



- NbSi209: 200g Ge with TES thermal sensor



- RED30 : 33 g Ge Al electrodes, NTD thermal sensor



KLM  $^{71}\text{Ge}$  from neutron activation  
3.7 GBq AmBe source ( $2 \times 10^5$  neutrons)

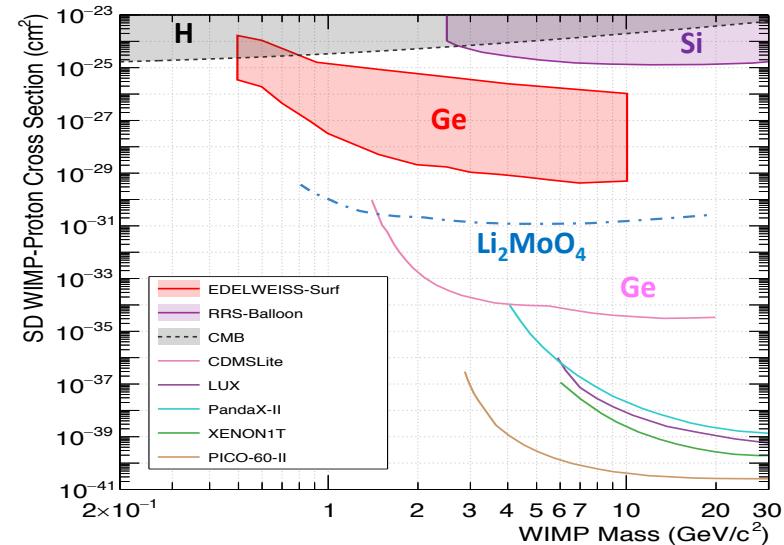
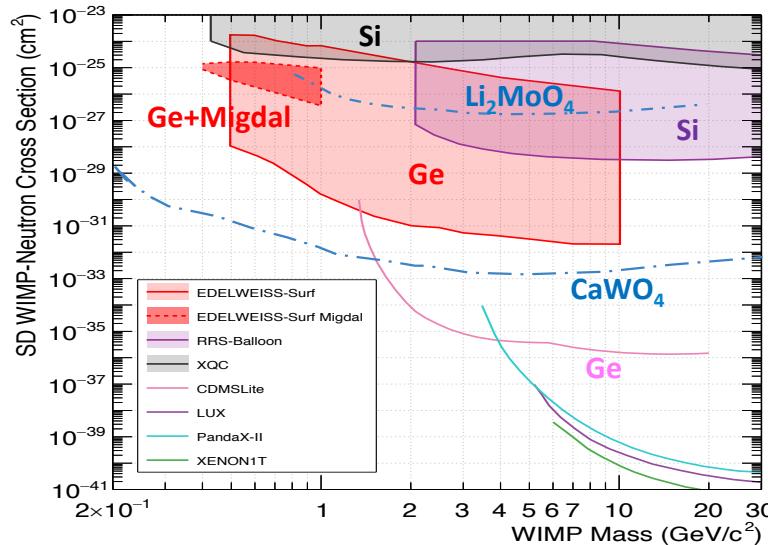
# Conclusions

- There is an increasing interest in the low-mass dark matter region motivated by lack of evidence of new physics at LHC (e.g. SUSY):  
→ *Beyond the standard WIMP Dark Matter scenario*
- **EDELWEISS-SubGeV** program aims at probing **MeV-GeV particles** via **ER and NR interactions** with new detectors:
  - Reduce detector mass to improve resolutions & thresholds -> **confirmed by EDELWEISS-Surf**
  - Particle ID and surface event rejection down to 50 eV<sub>NR</sub> (**Low Voltage**)
  - Single-e/h sensitivity on massive bolometers (**High Voltage**)
- **Low-voltage R&D program** focusing on front-end HEMT preamplifier and low-capacitance electrode design
  - objective:  $\sigma = 10 \text{ eV} (\text{phonon}) + 20 \text{ eV}_{\text{ee}} (\text{ionization})$
  - *Goal is to reach to reach  $O(10^{-43}) \text{ cm}^2$  with background rejection at 1 GeV, with 1 kg payload in one year at Modane*
- **High-voltage R&D program**, advancing well with near single-e/h sensitivity achieved on 33.4 g and 200 g Ge crystals operated at Modane.
- **New EDELWEISS science results expected in fall 2019 – STAY TUNED**

- BACKUP SLIDES

# Spin-dependent cases

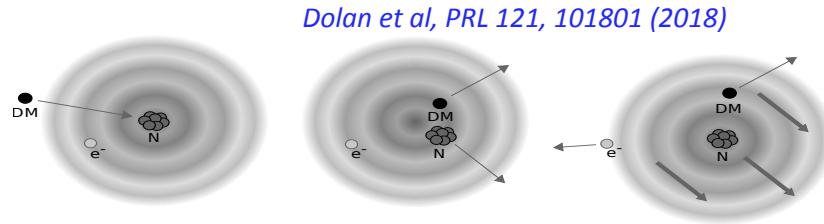
- Unfortunately,  $^{14}\text{N}$  has both p and n spin: *shielding from atmosphere*
- Large cross-section → dramatic ES effects (especially on Migdal limits)
- Blue dot-dashed: CRESST surface  $\text{Li}_2\text{MoO}_4$  [arXiv:1902.07587] and underground  $\text{CaWO}_4$  [arXiv: 1904.00498] – SIMP contour calcs. underway



Consider instead **inelastic scattering**. In particular, look for the possible ionisation of an electron after a DM-nucleus interaction - “**Migdal Effect**”

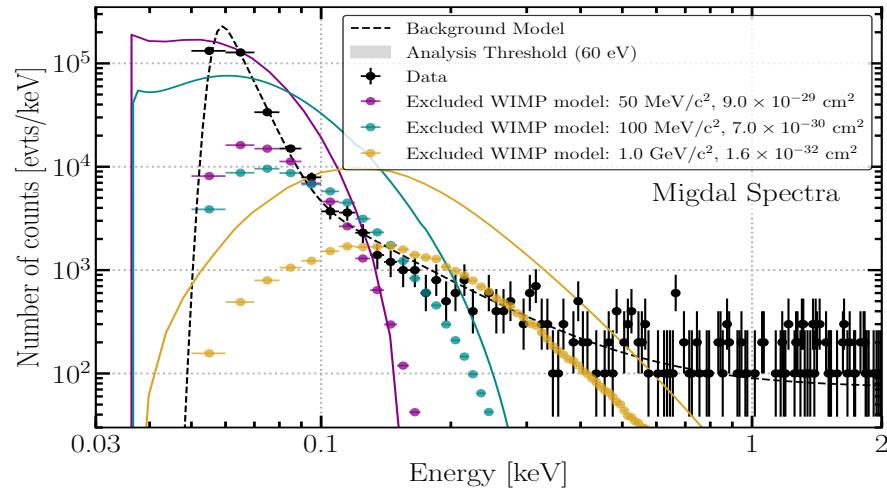
- Consider ionization effects of  $e^-$  cloud due to sudden boost of nucleus in DM collision

*Calculated in Ibe et al, JHEP 03 (2018) 194*

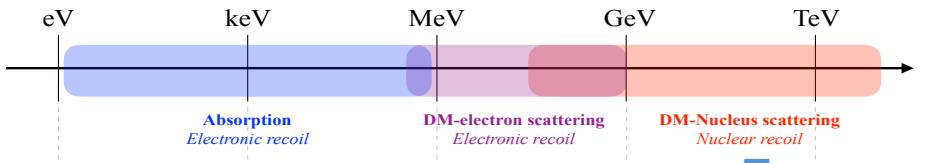


- Use M shell ( $n=3$ ) only in Ge
  - K, L electrons too tightly bound
  - $n=4$  affected by band structure
- Injection of electronic energy in the sub-keV to keV range
  - <1% probability
  - Negligible for  $>10 \text{ GeV}/c^2$  WIMPs
  - In RED20 (only heat): add energy from both NR and ER
  - Robust signal >100 eV even for DM masses <100 MeV/c<sup>2</sup>**

**Not yet observed, but calculable**



# Limit on Low-Mass WIMPs



- ▶ 8 selected detectors: low trigger thresholds and good noise conditions
- ▶ Resolution:  $\sigma_{ph} = 200$  eV,  $\sigma_{ion} = 220$  eV<sub>ee</sub>
- ▶ A total fiducial exposure of 496 kg.days after quality cuts
- ▶ Analysis with BDT/Profile Likelihood
- ▶ EDW-III Improvement by  $\times 20$  to  $\times 150$  between 7 and 10 GeV w.r.t EDW-II
- ▶ Limited by heat-only background  
→ identification and rejection using ionization channel

